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Electron trajectories and magnetotransport in nanopatterned graphene under commensurability conditions

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Commensurability oscillations in the magnetotransport of periodically patterned systems, emerging from the interplay of cyclotron orbit and pattern periodicity, are a benchmark of mesoscopic physics in electron gas systems. Exploiting similar effects in two-dimensional materials would allow exceptional control of electron behavior, but it is hindered by the requirement to maintain ballistic transport over large length scales. Recent experiments have overcome this obstacle and observed distinct magnetoresistance commensurability peaks for perforated graphene sheets (antidot lattices). Interpreting the exact mechanisms behind these peaks is of key importance, particularly in graphene, where a range of regimes are accessible by varying the electron density. In this work, a fully atomistic, device-based simulation of magnetoresistance experiments allows us to analyze both the resistance peaks and the current flow at commensurability conditions. Magnetoresistance spectra are found in excellent agreement with experiment, but we show that a semiclassical analysis, in terms of simple skipping or pinned orbits, is insufficient to fully describe the corresponding electron trajectories. Instead, a generalized mechanism in terms of states bound to individual antidots, or to groups of antidots, is required. Commensurability features are shown to arise when scattering between such states is enhanced. The emergence and suppression of commensurability peaks is explored for different antidot sizes, magnetic field strengths, and electron densities. The insights gained from our study will guide the design and optimization of future experiments with nanostructured graphene.

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I. INTRODUCTION

High-quality graphene samples with very large carrier mobilities provide an excellent platform to explore a range of physical phenomena emerging from the unique linear band structure near the Dirac point, such as Klein tunneling [1,2], the fractional quantum Hall effect [3], and electron lensing [4,5]. The ability to continuously tune the electron density in graphene also allows for a range of mesoscopic phenomena, previously examined in semiconductor two-dimensional (2D) electron gas systems, to be investigated more thoroughly and without the need for doping [6]. For example, the study of quantized conductance in confined one-dimensional channels relies on controlling the ratio between the system width and the Fermi wavelength. Typically, this involves changing the width using gate-defined potentials at the channel edges, but it can be achieved in graphene using a fixed-width nanoribbon and varying the Fermi wavelength by gating [7]. Ballistic graphene systems with variable electron densities are also ideal for probing mesoscopic classical physics effects—the realization of transverse magnetic focusing is a key example of this and allows electrons to be guided between two leads by varying their cyclotron radius in a magnetic field [8].

Antidot lattices provide perhaps the quintessential system for investigating two-dimensional mesoscopic phenomena [9–19]. They are realized in electron gases by a periodic array of strong repulsive potentials that scatter electrons traveling through the system. Hall bar transport measurements, performed in the presence of a perpendicular magnetic field, reveal a range of features. When the cyclotron radius is large enough to scatter electrons between antidots, successive scatterings can connect both sides of the device, introducing backscattering and removing the quantized edge transport of the quantum Hall regime (QHR). Most cyclotron radii in this regime lead to chaotic trajectories in the device bulk. However, when the cyclotron radius is commensurate with important system length scales, prominent new peaks and (nonquantized) plateaus emerge in the longitudinal and Hall resistances, $R_{xx}$ and $R_{xy}$, respectively. These are typically associated with semiclassical electron orbits that are pinned around individual or groups of antidots [shown by green circles in Fig. 1(a)] or skipping between nearby antidots [shown by the orange trajectory in Fig. 1(a)]. Fine Aharonov-Bohm (AB) oscillations on top of these commensurability features are associated with quantization of the electron orbits [20]. For high enough magnetic fields, the cyclotron radius is too small to cause scattering between antidots, and the QHR is mostly restored apart from exponentially suppressed quantum tunneling between states localized near individual antidots [21,22].

Gate potentials are inefficient at repelling electrons in graphene due to Klein tunneling [1], and so graphene antidot lattices (GALs) consist instead of periodic perforations in graphene sheets. The electronic properties of GALs and, in
particular, the dependence of band gaps on geometry have been the subject of intensive research [23,24]. Moreover, the influence of magnetic fields on perfectly periodic GALs and isolated antidots has been studied at the level of full atomistic approaches [25], the Dirac approximation [26], or the simple gapped graphene model [27]. Experimental fabrication of GALs involves invasive techniques such as electron beam or block copolymer lithography [28–37]. A major issue is the deterioration of the graphene sheet quality and the difficulty in maintaining a uniform size and separation of antidots throughout the lattice. Indeed, the band-gap behavior predicted for certain lattice geometries [23,24,38–45] is particularly sensitive to small levels of geometric disorder, which may not be possible to eliminate in experiment [46–51]. Although such uniformity is not an essential ingredient for commensurability oscillations, invasive etching processes usually reduce the mean free path significantly so that electrons are principally scattered by defects and not antidots, thus suppressing commensurability effects. By encapsulating graphene in hexagonal boron nitride (hBN) during the nanopatterning step, Sandner et al. [52] demonstrated that the sample quality can be protected, and consequently they observed pronounced commensurability peaks that they associated with orbits around one, two, or four antidots in a square lattice. A contemporaneous study by Yagi et al. [53], using a different etching technique, found commensurability features in triangular lattices with smaller mean free paths, suggesting that scattering between nearest-neighbor antidots plays a key role.

To clarify the exact mechanisms behind these commensurability peaks, and to determine the electron trajectories through such systems, we perform large-scale atomistic transport simulations of graphene antidot lattice devices. An excellent agreement is found in both the relative positions and the magnitudes of commensurability peaks with recent experimental results [52]. Furthermore, by mapping the current flow, we can identify the electron trajectories associated with each peak. The classical picture of skipping or pinned orbits is too simple to fully describe the resulting electron flow patterns. An alternative analysis, in terms of scattering between states bound to individual antidots, shows that a generalized skipping orbit picture can explain the first two commensurability peaks. Higher-order peaks are understood in terms of quasipinned orbits around groups of antidots. Both mechanisms act to divert electrons away from the sample edges and into the bulk, and thus remove the ballistic edge transport of the quantum Hall regime. Finally, we examine the emergence and suppression of the peaks at different antidot sizes, and the experimentally relevant transition between classical and quantum regimes.

II. METHODS

We consider a six-probe Hall bar structure as shown schematically in Fig. 1(a). The main device region is constructed from an ~100 nm wide zigzag nanoribbon with a 960-atom unit cell. The six external leads consist of semi-infinite nanoribbons. A few atomic rows from the top and bottom armchair nanoribbon probes are included in the device region for mapping purposes. The main device region consists of a 4 × 8 array of antidots with a center-to-center separation of \( D \approx 26 \text{ nm} \). We focus on antidots with diameter \( d \approx 10 \text{ nm} \), as shown in this schematic, but we also consider antidots of different sizes. The total number of atoms in a typical simulation is between 750 000 and 950 000.

The electronic structure of graphene is described by a single \( \pi \)-orbital tight-binding Hamiltonian \( H = \sum_{i<j} t_{ij}(B) \hat{c}_i \hat{c}_j^\dagger \), where the sum is taken over nearest-neighbor sites only. The nearest-neighbor hopping parameter \( t_{ij}(B) \) takes the value \( t_{ij}(0) = t = \pm 2.7 \text{ eV} \) in the absence of a magnetic field. Throughout this work, we will use \( |r| \) as the unit of energy. The effect of a magnetic field is included using the Peierls’ phase approach, which places a field-dependent phase factor into the hopping parameters,

\[
t_{ij}(B) = t_{ij}(0)e^{i\frac{\Theta_{ij}}{\Theta_{i}}},
\]

where \( \Theta_{ij} = \oint_{r_i} A(r') \cdot dr' \), and \( r_i \) is the position vector of site \( i \) and we have a choice of gauge fields \( A \) that give \( B = \nabla \times A = B_\perp \). The commonly used Landau gauge \( A_0 = -By\hat{y} \) maintains periodicity along one direction. However, a more complicated prescription, taking advantage of periodicity in the graphene leads in both the \( x \) and \( y \) directions [54], is employed for our Hall bar calculations and is outlined in more detail in Appendix A. Removing carbon atoms from the antidot

![Figure 1](https://example.com/figure1.png)

**FIG. 1.** (a) Simulated device geometry: the central graphene region (gray) contains an 8 × 4 antidot array with diameter \( d \approx 10 \text{ nm} \) and separation \( D \approx 26 \text{ nm} \). External leads (0–5) are shown in red. Classical commensurability orbits are highlighted—skipping (s; orange), pinned around dots (1, 2, 4; green), or pinned between dots (1α; blue). (b) Dispersive edge states in the quantum Hall regime occupy the blue shaded region near an edge. Classically, consecutive skipping orbits (dashed red trajectories) combine to give a net current flow (gray arrows). The edge state region width, \( 2r_e \), is given by the furthest extent of a cyclotron orbit that intersects the edge. (c) A ring of bound states, consisting of orbits trapped by the antidot, forms around an antidot in a magnetic field. These are nondispersive unless coupled to other states by additional scattering.
regions corresponds to the removal of the associated rows and columns from the system Hamiltonian. We also remove dangling atoms with only a single remaining neighboring atom. Any dangling $\sigma$ bonds for a carbon atom with only two neighboring carbon atoms are assumed to be passivated by hydrogen so that the $\pi$ bands are unaffected.

The zero-temperature currents $I_p$ and potentials $V_p$ in each lead $p$ are related via the multiterminal Landauer-Buttiker relation

$$I_p = \frac{2e}{h} \sum_{q} (T_{pq} V_p - T_{qp} V_q),$$

where the transmissions are given by the Caroli formula $T_{pq} = \text{Tr}(G^K \Gamma_q G^A \Gamma_p)$. Here, $G^K$ and $G^A$ are the retarded and advanced Green’s functions, respectively, and $\Gamma_p$ is the broadening matrix associated with lead $p$. Defining $T_{pq} = \delta_{pq} \sum_r T_{rp} - T_{pq}$ gives a direct relation $I = TV$, where $I$ and $V$ are column vectors. To calculate the longitudinal and Hall resistances, we fix a potential difference between the left and right leads, and we set the net current in the top and bottom floating probes to zero. Solving for the net current flowing through the system, $I$, and the potentials at the top and bottom probes, $V_{2-5}$, yields the longitudinal and Hall resistances

$$R_{xx} = \frac{V_2 - V_3}{I}, \quad R_{xy} = \frac{V_2 - V_4}{I}.$$  

The Green’s functions required are calculated using efficient recursive techniques to return the matrix elements required.

Fine oscillations, similar to those noted in Ref. [52], are observed superimposed on the simulated commensurability peaks. A Fourier analysis confirms these to be mostly Aharonov-Bohm in origin, with a high weight at periods $\sim \pi$. Further details are given in Appendix B. Current heat maps in this work show the spatial distribution of current in the system, and they represent the magnitude of the local current using brighter (darker) colors for larger (smaller) magnitudes. Arrows are superimposed in some zoomed current maps to illustrate the current flow direction. In both cases, a spatial averaging is applied to produce current map plots with suitable resolution and clarity.

### III. RESULTS AND DISCUSSION

#### A. Magnetoresistance commensurability peaks

The six-probe Hall bar device employed in our simulations is shown in Fig. 1(a), together with schematics of different semiclassical pinned and skipping orbits. We consider a system with antidot separation $D \approx 26$ nm and diameter $d \approx 10$ nm, with mild geometric disorder in antidot size and position. The simulated longitudinal resistance $R_{xx}$ of this system is shown in Fig. 2(a) as a function of the perpendicular magnetic field $B$. The Fermi wavelength is set much smaller than GAL length scales ($\lambda_F = \frac{\hbar}{e B_F} \sim 3$ nm for $E_F = 0.4|t|$) to ensure we are outside the quantum regime, i.e., $\lambda_F \approx D, d$. The cyclotron radius, determined by the magnetic field strength, is given by

$$r_c = \frac{E_F}{v_F e B}.$$  

The fully atomistic nature of our calculations limits the size and separation of our antidots, hence quite a large $E_F$ is used to achieve an appropriate Fermi wavelength. A large magnetic field is then required in Eq. (4) to enter the commensurability regime $r_c \sim D$. In fact, the condition $r_c = \frac{D}{2}$, associated with the primary commensurability peak, occurs at $B_0 \approx 97$ T for our system. Experimental systems typically have $D \gtrsim 100$ nm and $d \sim 30$ nm, so that the commensurability regime is accessible for smaller $E_F$ and with $B < 10$ T. The experimental and theoretical systems are directly related by scaling—from Eq. (4) we expect $B_0 \sim \frac{D}{r_c}$ when the ratio $\frac{D}{r_c}$ is kept fixed—and the same qualitative processes determine electron behavior in each. Indeed, the experimental peak observed in Ref. [52] at $B/B_0 = 0.75$ is reproduced from Sandner et al. [52]—an excellent match is noted with the simulation.
\( B_0 \approx 3.6 \text{T} \) and \( \lambda_F \approx 21 \text{ nm} \) corresponds to \( r_c \approx 54 \text{ nm} \)—very near the expected value \( r_c = 50 \text{ nm} \). Magnetic fields are plotted here in terms of \( B_0 \) for easy comparison of results at different scales and energies. In our simulations, \( B_0 \) is calculated using Eq. (4).

The \( R_{xx} \) curve in Fig. 2 contains (at least) three prominent peak features, which we denote as commensurability peaks \( C_1 \), \( C_2 \), and \( C_3 \). \( C_1 \) occurs almost precisely at the expected \( B_0 \). The validity of our results is confirmed by a direct comparison with the experimental data of Sandner et al. [32] in a system with \( D \sim 100 \text{ nm}, d \sim 30 \text{ nm} \), which is reproduced in Fig. 2(b). \( B_0 \) is set as the peak maximum for the experimental data. An excellent agreement is noted between simulation and experiment, suggesting a universal behavior at different scales once the ratios between cyclotron radii and system dimensions are similar. The three peaks in \( R_{xx} \) coincide with new steplike features in \( R_{xy} \) (see Appendix C), a feature that is also visible in the experiment and in previous experimental and theoretical studies in two-dimensional electron gases (2DEGs) [9,10].

Shubnikov–de Haas oscillations are visible for high fields in both curves. Their spacing follows the Landau levels, and not \( \delta \). The net circulation direction is the same as that of single localized orbits and is shown in Fig. 1(c) by gray arrows. We note that these regions are not the same as the 1-type pinned orbit (Fig. 1), which consist of single semiclassical orbits with radius \( r_c \) encircling, but not scattering from, an antidot. Unlike QHR edge states, antidot ring states are nondispersive and are bound to individual antidots in the absence of additional scattering centers. We now consider the current flow in antidot Hall bar devices as the cyclotron radius increases (magnetic field decreases).

**B. Current flow for large magnetic fields**

There is no interaction between the QHR edge states and the antidot region for very large fields, and the current flow is unchanged relative to an unpatterned device. Changes in bulk state distribution, due to broken LL degeneracy, can manifest as a broadening of Shubnikov–de Haas oscillations in \( R_{xy} \). Significant changes from the QHR occur when \( r_c \) is increased so that the ring associated with an antidot intersects another antidot or the device edge.

As \( B \) is decreased, \( r_c \) becomes large enough to allow hybridization between quantum Hall edge states and the rings associated with the first row of antidots. This modified

\[ \begin{align*}
\text{MQHR} & \quad (a,d) \\
\text{C}_1 & \quad (b) \\
\text{C}_2 & \quad (c) \\
\text{C}_3 & \quad (e) \\
\end{align*} \]

**FIG. 3.** Schematics and current maps for the modified quantum Hall (MQHR) and first commensurability peak (\( C_1 \)) regimes. (a,d) Schematics showing the extent of edge and/or ring states (blue shaded areas) in the given regime, net current flow directions (gray, pink arrows), and individual semiclassical trajectories (red dashed and solid lines). The thicker green circle in (d) shows the expected size of the 1\( \alpha \) type pinned orbit at this magnetic field value. (b,e) Current heat maps of the entire device. (c,f) Zoomed region of heat maps in (b,e) with current flow directions illustrated by arrows.
quantum Hall regime (MQHR) is considered on the left of Fig. 3, where $B \approx 1.85B_0$. At this field, the rings associated with the top row of antidots intersect the top edge, and similarly the edge-state region intersects these antidots [Fig. 3(a)]. However, while the rings of neighboring antidots overlap, they do not intersect the neighboring antidots themselves. The current map in Fig. 3(b), and the zoom in Fig. 3(c), show that the incoming edge current from the left is split at the first antidot it encounters. The current then flows in a broader edge channel encompassing the first row of antidots, and which is a superposition of the QHR edge-state region and the rings associated with top-row antidots. New dispersive states, which now also flow around the first row of antidots, are formed by coupling between states in these regions due to edge and antidot scattering. The key factor is that the overlap region between the QHR edge state and an antidot ring contains scatterers, namely the edge and antidot themselves. We also note that the overlap between neighboring rings on the top row is intersected by the top edge, so that states previously bound to individual antidots can couple to each other due to the edge. No such hybridization occurs between the bound states associated with antidots in lower rows, as their overlap regions are devoid of scatterers, so these states remain localized and do not contribute to current flow in the system.

C. Current flow near the principal peak

At larger $r_c$, antidot rings impinge not only on each other, but on the edges of the neighboring antidots themselves. Semiclassically, this begins once a single orbit can cross the but on the edges of the neighboring antidots themselves. The current map in Fig. 3(b), and the zoom in Fig. 3(c), show that the incoming edge current from the left is split at the first antidot it encounters. The current then flows in a broader edge channel encompassing the first row of antidots, and which is a superposition of the QHR edge-state region and the rings associated with top-row antidots. New dispersive states, which now also flow around the first row of antidots, are formed by coupling between states in these regions due to edge and antidot scattering. The key factor is that the overlap region between the QHR edge state and an antidot ring contains scatterers, namely the edge and antidot themselves. We also note that the overlap between neighboring rings on the top row is intersected by the top edge, so that states previously bound to individual antidots can couple to each other due to the edge. No such hybridization occurs between the bound states associated with antidots in lower rows, as their overlap regions are devoid of scatterers, so these states remain localized and do not contribute to current flow in the system.

The position of $C_2$ at $0.6B_0 < B < 0.75B_0$, with a maximum at $B \approx 0.68B_0$, suggests an extension of the $C_1$ mechanism to 2NN antidots. At $2r_c = \sqrt{2}D$ ($B \approx 0.71B_0$), an antidot ring entirely encompasses 2NN antidots [Fig. 4(a)]. This gives direct coupling between states bound to antidots separated diagonally, but it is also the condition for maximum
indirect coupling between nearest-neighboring antidots due to scattering from a third antidot. In Fig. 4(a), this corresponds to increased coupling between right-moving states bound to $\mathcal{X}$ and its neighbor to the right, $\mathcal{R}$, due to the presence of $\mathcal{D}$ (and also $\mathcal{B}$). Similarly, coupling is increased between down-moving states around $\mathcal{X}$ and $\mathcal{B}$ (due to $\mathcal{D'}$ and $\mathcal{L}$). The gray (around $\mathcal{X}$) and pink (around $\mathcal{R}$ and $\mathcal{B}$) arrows suggest the formation of horizontal and vertical conducting channels between antidots. Clear signatures of horizontal channels are observed in Figs. 4(b) and 4(c). The high-field onset of $C_2$ at $B \sim 0.75 B_0$ is below that expected by assuming that significant enhancement occurs once orbit sizes allow scattering from the preferential side of the antidot. However, unlike the $C_1$ case, other antidots block many of these trajectories, particularly for smaller orbits, resulting in a narrower $C_2$ peak. $2$NN antidots thus influence commensurability peaks in two ways: first by enhancing certain $C_1$ channels at small $r_c$, and secondly by giving rise to $C_2$ channels at higher $r_c$.

At even larger $r_c$, it is difficult to associate rings with individual antidots. Each ring surrounds several antidots and has large overlaps with many other rings, leading to a large degree of delocalization. This is consistent with a wide distribution of dispersive bulk states, and a reduced contribution from ballistic edge transport to transmission between probes 2 and 3. $R_{44}$ therefore remains reasonably large and constant over the low-field range. This prediction is confirmed in both simulation and experiment, further validating our analysis in terms of antidot quasibound states. $C_3$ occurs as a reasonably wide peak superimposed on this low-field plateau between $0.3 B_0 \lesssim B \lesssim 0.5 B_0$, corresponding to $3.33 D \lesssim 2 r_c \lesssim 2 D$. $4$-type pinned orbits, like that shown in solid green in Fig. 4(d), are predicted to occur in a range centered around $B \sim 0.44 B_0$. This orbit does not intersect an antidot, so it is not expected to couple with other states to become dispersive. However, a range of “quasipinned” orbits with the same radius (such as that shown in dashed green), but asymmetrically positioned relative to the antidots they surround, do intersect antidots. These orbits collectively fill the green shaded areas to form a wide loop of hybridized states, in addition to individual localized orbits, circulating in this region. Furthermore, the antidots marked x hybridize states in neighboring four-antidot loops. Electrons can therefore migrate through the device by circling consecutive $4$-antidot loops in turn. Such behavior is clearly visible in Figs. 4(e) and 4(f), where a migrating current around groups of four antidots in the central rows of the device is noted. The net effect is to carry current away from the edges and into the device bulk, increasing the resistance between pairs of edge probes. At nearby fields, clear four-ring orbits are less visible, but the net effect of increased current in the bulk at the expense of edge channels remains evident.

E. Commensurability peak mechanisms

The mechanisms behind $C_1$ and $C_2$ can both be considered generalizations of the semiclassical “skipping” orbit picture. In both cases, current percolates through a network of quasilocalized states surrounding individual antidots. At the principal peak $C_1$, coupling between states at neighboring antidots is enhanced due to direct scattering by one antidot of electrons associated with the other. The net trajectories resemble semiclassical runaway orbits, but current profiles for small antidots have an angular shape, as shown in Fig. 5(b). This is consistent with hybridization between the rings localized around neighboring antidots and not with a simple single skip mechanism.

In the case of $C_2$, the peak is not solely due to a runaway orbit scenario between pairs of second nearest neighbors, rather it is also associated with runaway orbits between neighboring antidots, due to additional scattering from $2$NN antidots. We can rule out dominant contributions from $2$-type quasipinned orbits as the expected peak position for such orbits ($B \sim 0.62 B_0$) is to the low-field side of the peak in our simulations.

Meanwhile, the $C_3$ peak emerges due to quasipinned-type orbits, whose net effect is to divert electrons away from edge states and into bulk channels. Simulation of higher-order orbits, similar to $C_3$ but pinned around larger groups of antidots, is nontrivial in our geometry as orbits around nine or more antidots begin to intersect the edges of the device. Such orbits are also difficult to achieve experimentally.
as even greater mean free paths are required. Nonetheless, enhancement of $R_{xx}$ should occur in principle at these radii also. Indeed, a slight peak is present at $\sim 0.1B_0$ in both theory and experiment.

F. Geometry and gating effects

In Fig. 5(a), the antidot diameter $d$ is varied between 5 and 14 nm, equivalent to aspect ratios $d/D \sim 0.2 - 0.58$. Each bold curve is an average over several instances of mild geometric disorder, with individual configurations shown by the lighter curves. These curves are not shifted relative to each other along the $R_{xx}$ axis, but rather the magnitude of $R_{xx}$ increases significantly with antidot size. Larger antidots act as stronger scatterers and divert more incoming edge current into the bulk of the device. $C_1$ is prominent at $B = B_0$ for all but the smallest antidot diameters considered, but it is particularly sharp near the $d \approx 10$ nm case considered in detail in the previous section. This may be due to the enhanced scattering caused by 2NN antidots at this aspect ratio. We note that this antidot size also gives the clearest $C_2$ peak. At smaller sizes, the peak is somewhat difficult to detect due to the superposition of quantum oscillations, which are related to the underlying Shubnikov–de Haas oscillations [19]. At larger sizes, it is less prominent due to the blocking effect of nearest-neighbor antidots and is largely swallowed by the broadening $C_1$ peak.

The positions of all three commensurability peaks remains quite consistent with the predicted values (gray vertical lines) over a wide range of antidot diameters.

Varying the Fermi wavelength of graphene by gating allows both the classical ($\lambda_F \ll l$, where $l$ is a typical system length scale) and quantum ($\lambda_F \sim l$) regimes to be accessed with the same sample. In Figs. 6(a)–6(d), we examine $R_{xx}$ for the $d \approx 10$ nm antidot system, with and without geometric disorder, as $\lambda_F$ increases toward the quantum regime. Red curves in these plots show the cases without geometric disorder—averaged and individual disordered cases are shown by solid black and light gray curves, respectively. Figure 6(a), the case considered throughout this work, shows very little deviation between the curves, suggesting that the peak features are extremely robust against disorder. As $\lambda_F$ is increased, it becomes similar to both $d$ ($\sim 0.4D$) and the antidot neck width ($\sim 0.6D$) and so quantum interference plays a more prominent role. This is reflected in the increased sample-to-sample fluctuations in disordered cases and a growing discrepancy between pristine and disordered results. Figure 6(e) shows local current flow at $B = B_0$ for the largest $\lambda_F$ considered. “Skipping-orbit”-like flows, seen previously for smaller $\lambda_F$, are entirely absent, replaced by a complex pattern of vortices arising from quantum-interference effects.

IV. CONCLUSION

We have demonstrated the emergence of magnetic commensurability effects in graphene antidot lattices from purely quantum-mechanical multiprobe transport simulations. Peak positions and relative magnitudes are in excellent agreement with recent experimental results on the same system. By examining the dependence of peak positions on cyclotron radius and aspect ratio, and by mapping the local current

FIG. 5. (a) $R_{xx}$ for a range of antidot diameters, each dark curve in an average over individual instances of mild geometric disorder (light curves). Vertical lines show the expected peak positions. (b) Current map zoom at $C_1$ for $d \approx 7$ nm showing a current path with a more angular profile than that in Fig. 3(f), corresponding to flow between rings of neighboring antidots.

FIG. 6. (a)–(d) $R_{xx}$ at four different Fermi energies, corresponding to an increase in Fermi wavelength. Red curves show the pristine system, whereas black curves are the result of averaging five configurations with mild position and radial disorder, with individual configurations in gray. (e) Current map at $B = B_0$ for $E_F = 0.1|t|$. Skipping orbits are notably absent, replaced by vortices induced by quantum interference.
behavior at important values, we are able to explain some subtle details of the mechanisms behind commensurability peaks in the longitudinal resistance. The two highest field commensurability peaks can be understood in terms of scattering between localized states formed around individual antidots in the presence of a magnetic field. This mechanism is enhanced when these states intersect with nearest- or next-nearest-neighbor antidots. Higher-order peaks are associated with migration between quasi-continuous orbits around groups of multiple antidots, with scattering from nearby antidots again playing a key role. We also examined the evolution of the magneto-resistance as different length scales in the system are varied. The appearance of the second commensurability peak is sensitive to the antidot lattice aspect ratio. Finally, we demonstrated how the transition between classical and quantum regimes can be tuned by gating. The onset of the quantum regime at Fermi wavelengths approaching system length scales was associated with the suppression of commensurability features and a marked increase in the effect of geometric disorders. We believe that our results can act as a guide to interpreting commensurability features in future experiments.

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APPENDIX A: PEIERLS’ PHASE APPROACH

AND CHOICE OF GAUGE

The effect of a magnetic field on the behavior of electrons described within a tight-binding model is included using the Peierls’ phase approach. This involves placing a field-dependent phase factor into the tight-binding hopping parameters, so that

$$t_{ij}(B) \rightarrow t_{ij}(0)e^{\frac{2\pi i}{\Theta_{ij}}},$$  \hspace{1cm} (A1)

where

$$\Theta_{ij} = \int_{r_i}^{r_j} \mathbf{A}(r') \cdot dr' = \int_0^1 \left( r_j - r_i \right) \cdot \mathbf{A} [ r_i + \lambda ( r_j - r_i ) ] d\lambda.$$ \hspace{1cm} (A2)

Note that since the phase factor depends on the vector potential \( \mathbf{A} \), where \( \mathbf{B} = \mathbf{V} \times \mathbf{A} \), we have freedom with regard to which particular gauge to choose. For fields perpendicular to the two-dimensional plane (\( \mathbf{B} = B\hat{z} \)), we usually pick the Landau

![FIG. 7. System schematic showing an example of gauge switching points.](image)

gauge

$$\mathbf{A}_0 = -By\hat{x},$$ \hspace{1cm} (A3)

which gives

$$\Theta_{ij} = -B \frac{y_i + y_j}{2} (x_j - x_i) \equiv -B\tilde{y}\Delta x.$$ \hspace{1cm} (A4)

This gauge proves useful for dealing with leads in the \( x \) direction, as the phase term only depends on the difference in \( x \) coordinates and not their absolute value—thus periodic cells can be used within recursive Green’s functions methods to calculate the self-energies for leads with this orientation. Similarly, for leads aligned with the \( y \) axis, we can use the gauge \( \mathbf{A}_\perp = Bx\hat{y} \), for which \( \Theta_{ij} = B\tilde{x}\Delta y \), allowing periodic cells in the \( y \) direction and a phase that only depends on the absolute value of the \( x \) coordinate.

For our Hall bar setup, shown schematically in Fig. 7, containing leads with both \( x \) (0,1) and \( y \) (2,3,4,5) orientations, we follow the approach outlined by Baranger and Stone [54], which allows us to avoid of periodicity in every lead of the system. We add a gauge transformation to the initial gauge in Eq. (A3) so that

$$\mathbf{A} = \mathbf{A}_0 + \nabla \tilde{f}(x,y).$$ \hspace{1cm} (A5)

It is clear that the magnetic field is gauge-invariant under a transformation of this kind. Ideally, we need an \( \tilde{f}(x,y) \) that gives \( \mathbf{A} = \mathbf{A}_0 \) in leads 0 and 1 and \( \mathbf{A} = \mathbf{A}_\perp \) in leads 2–5. We define the function

$$f(x,y) \equiv Bxy,$$ \hspace{1cm} (A6)

and note that \( \nabla f = Bx\hat{x} + Bx\hat{y} \) and \( \mathbf{A} + \nabla f = \mathbf{A}_\perp \), allowing us to switch between the two gauges of interest.

We now introduce a weight function \( W(x) \) that allows us to smoothly turn on and off the gauge transformation and define

$$\tilde{f}(x,y) = W(x)f(x,y).$$ \hspace{1cm} (A7)

\( W \) should take the value 0.0 in leads 0 and 1 and the value 1.0 in the other leads. Outside this region it should vary smoothly between these values with both \( W(x) \) and \( W'(x) = \frac{dW}{dx} \) continuous. This gives

$$\mathbf{A} = \{ [W(x) - 1]By + W(x)Bxy\hat{x} + W(x)Bx\hat{y} \},$$ \hspace{1cm} (A8)

which we can easily confirm gives the required vector potential when \( W(x) = 0 \) or 1 and \( W'(x) = 0 \), and further that \( \nabla \times \mathbf{A} = B\hat{z} \) at all points.
For our Hall bar system, we include short buffer regions ($x_b < x < x_d$ and $x_c < x < x_d$ in Fig. 7) between the horizontal leads and the central device region, where we switch between the two gauges. We use a smooth step function

$$S_z(z) = 3z^2 - 2z,$$

(A9)

where $S_z(0) = 0$, $S_z(1) = 1$, and $S'_z(0) = 0$ to define the weight function in the different regions of our system:

$$W(x) = \begin{cases} 
0 & \text{if } x \leq x_a, \\
S_z \left( \frac{x-x_a}{x_d-x_a} \right) & \text{if } x_a < x < x_b, \\
1 & \text{if } x_b \leq x \leq x_c, \\
1 - S_z \left( \frac{x-x_c}{x_d-x_c} \right) & \text{if } x_c < x < x_d, \\
0 & \text{if } x \geq x_d. 
\end{cases}$$

(A10)

With this definition, the phase factors entering in Eq. (A1) can be written explicitly as

$$\Theta_{ij} = \begin{cases} \frac{B}{2\pi} \Delta x \left[ \begin{array}{c} 2\Delta y x_i (x_i - x_a)^2(3L_{cd} - 2x_i + 2x_d) \\
-\Delta x \Delta y (L_{cd}^3 + 4(x_i - x_a)^2(4x_i - x_a) - 6L_{cd}(3x_i^2 - 4x_i x_a + x_a^2)) \\
-2\Delta x y_i (L_{cd} - x_i + x_a)(L_{cd}^2 + L_{cd}(x_i - x_a) - 2(4x_i^2 - 5x_i x_a + x_a^2)) \\
-4(\Delta x)^2 y_i + 4(\Delta x)^2 (3L_{cd} - 8x_i + 6x_a)(y_i + \Delta y) \\
+6(\Delta x)^2 (3L_{cd} - 4x_i^2 - 2L_{cd} x_i + 6x_i x_a - 2x_a^2)(y_i + \Delta y) \\
-2\Delta x \Delta y x_i (3L_{cd} x_i - 4x_i^2 - 2L_{cd} x_i + 6x_i x_a - 2x_a^2)(x_i + \Delta y) \\
\end{array} \right] \\
\frac{B}{2\pi} \Delta x \left[ \begin{array}{c} 2\Delta y x_i (L_{cd} - x_i + x_c)^2(L_{cd} + 2x_i - 2x_c) \\
+2\Delta x y_i (L_{cd} + 4(x_i - x_c)^2(4x_i - x_c) - 6L_{cd}(3x_i^2 - 4x_i x_c + x_c^2)) \\
+2\Delta x y_i (x_i - x_c)(-9L_{cd} x_i + 8x_i^2 + 3L_{cd} x_i - 10x_i x_c + 2x_c^2) \\
+4(\Delta x)^2 y_i + 4(\Delta x)^2 (3L_{cd} - 8x_i + 6x_a)(y_i + \Delta y) \\
-6(\Delta x)^2 (3L_{cd} x_i - 4x_i^2 - 2L_{cd} x_i + 6x_i x_a - 2x_a^2)(y_i + \Delta y) \\
-2\Delta x \Delta y x_i (3L_{cd} x_i - 4x_i^2 - 2L_{cd} x_i + 6x_i x_a - 2x_a^2)(x_i + \Delta y) \\
\end{array} \right] \right] \\
\frac{B}{2\pi} \Delta x \end{cases}$$

if $x \leq x_a$, if $x_a < x < x_b$, if $x_b \leq x \leq x_c$, if $x_c < x < x_d$, if $x \geq x_d$.

The validity of this choice was confirmed by reproducing the quantum Hall effect result for pristine graphene and checking the independence of local current flow on the exact positions of the gauge switching points.

**APPENDIX B: CURRENT MAPS**

The current crossing a single bond between sites $i$ and $j$ is given in its most general form by [55,58,59]

$$I_{ij} = \frac{2e}{h} \int \frac{dE}{2\pi} (t_{ji}^+ G_{ji}^- - t_{ji}^- G_{ji}^+),$$

(B1)

where the lesser Green’s function can be expressed in terms of the retarded and advanced Green’s functions as

$$G^<(E) = G^R(E) \Sigma^<(E) G^A(E),$$

(B2)

and $\Sigma^<(E) = i \sum_p \Gamma_p(E) f_p(E)$, where $\Gamma_p(E) = i [\Sigma_p(E) - \Sigma_p^j(E)]$ is the broadening and $f_p(E) = f(E - eV_p)$ is the Fermi function associated with each lead $p$.

With

$$G^<(E) = i \sum_p f_p(E) G^R(E) \Gamma_p(E) G^A(E),$$

(B3)

we can write (omitting $E$ dependence for conciseness)

$$t_{ji}^+ G_{ji}^- - t_{ji}^- G_{ji}^+ = -2 \text{Im} \left[ \sum_p f_p t_{ij}^+ G^R \Gamma p G^A \right],$$

where we used $\Gamma^p = \Gamma^R$ and $G^A = G^R$. For the two-probe case, with $p = \{L,R\}$ (and assuming $\mu_L > \mu_R$),

$$\sum_p f_p G^R \Gamma_p G^A = f_L G^R \Gamma^L G^A + f_R G^R \Gamma^R G^A$$

$$= i f_R (G^R - G^A) + (f_L - f_R) G^R \Gamma^L G^A,$$

(B4)

which allows us to split the current into two components:

(i) The persistent, or equilibrium, current is given by

$$I_{ij}^{(\text{pers.})} = \frac{4e}{h} \int \frac{dE}{2\pi} (f_R) \text{Re}[t_{ij}^+ (G^R - G^A)_{ji}].$$

(B5)

We note that this component is independent of the chemical potential between leads, and it is present even in the absence of a bias. It does not contribute to the total current through the device. Furthermore, the integration involves energies in the Fermi sea below the bias window, and it is identically zero in the case of time-reversal symmetry.

(ii) The nonequilibrium, or total current-carrying, component is given by

$$I_{ij}^{(\text{eq.})} = \frac{-4e}{h} \int \frac{dE}{2\pi} (f_L - f_R) \text{Im}[t_{ij}^+ (G^R \Gamma^L G^A)_{ji}].$$

(B6)

It is carried by electrons at the Fermi surface, and it vanishes in the absence of a bias. It is this current that is relevant in this work, and the bond currents plotted in this paper neglect the persistent currents that do not contribute to the overall transport measurements.
To generalize to the case of \( N \) probes, we split \( G^{<} \) in a similar fashion to Eq. (B4) and write

\[
\sum_{p} f_{p} G^{R} \Gamma^{p} G^{A} = i f_{m} (G^{R} - G^{A}) + \sum_{p \neq m} (f_{p} - f_{m})G^{R} \Gamma^{p} G^{A},
\]

(B7)

where \( m \) is chosen such that \( \mu_{m} = \min(\mu_{i}) \) for \( i \in \{0, \ldots, N - 1\} \). The total nonequilibrium bond current in a multiterminal system is then given by

\[
f_{ij}^{(e-\text{eq.})} = \frac{-4e}{h} \int \frac{dE}{2\pi} \sum_{p \neq m} (f_{p} - f_{m}) \text{Im}[i_{ij}(G^{R} \Gamma^{p} G^{A})_{ji}].
\]

(B8)

In this work, we take the low-temperature limit so that the Fermi functions become step functions. Furthermore, we assume that an infinitesimal bias is applied, so that all the quantities in Eq. (B8) are evaluated at the Fermi energy. Up to a constant, the bond currents are then given by

\[
f_{ij}^{(e-\text{eq.})} \sim \sum_{p \neq m} (V_{P} - V_{m}) \text{Im}[i_{ij}(G^{R} \Gamma^{p} G^{A})_{ji}].
\]

(B9)

APPENDIX C: LONGITUDINAL, HALL, AND TWO-POINT RESISTANCES

In Fig. 8, we compare the longitudinal \( R_{xx} \) resistance from Fig. 2(a) in the body of the paper with a two-probe resistance measurement taken for an identical device in a nanoribbon geometry (i.e., without the top and bottom pairs of probes). We note that although signatures of the commensurability lattices. 

steps are not quantized or related to the underlying quantum Hall edge states. This is clearly seen by comparing the \( R_{xy} \) for GALs with that for a pristine nanoribbon (light red curve), where the quantum Hall plateaus are clearly visible and scale very differently in height and width to the new antidot features.

The two-point measurement \( R_{xy} \) mixes the peak structure of \( R_{xx} \) with the step features of \( R_{xy} \). Furthermore, the Hall bar setup helps to filter out contact resistance effects, which can also obscure commensurability features. Nonetheless, commensurability features, and particularly the \( C_{1} \) peak, may be visible in two-probe resistance measurements of antidot lattices.

\[\text{References}\]